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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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HUFA75321D3ST_F085



Data Sheet

<u>April</u> 2013

20A, 55V, 0.036 Ohm, N-Channel UltraFET Power MOSFETs



These N-Channel power MOSFETs are manufactured using the innovative UltraFET® process. This advanced process technology

achieves the lowest possible on-resistance per silicon area, resulting in outstanding performance. This device is capable of withstanding high energy in the avalanche mode and the diode exhibits very low reverse recovery time and stored charge. It was designed for use in applications where power efficiency is important, such as switching regulators, switching converters, motor drivers, relay drivers, lowvoltage bus switches, and power management in portable and battery-operated products.

Formerly developmental type TA75321.

Ordering Information

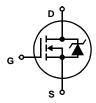
PART NUMBER	PACKAGE	BRAND		
HUFA75321D3ST_F085	TO-252AA	75321D		

NOTE: When ordering, use the entire part number.

Features

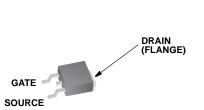
- 20A, 55V
- Simulation Models
 - Temperature Compensating PSPICE® and SABER™ Models
 - Thermal Impedance SPICE and SABER Models Available on the web at: www.fairchildsemi.com
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
 - TB334, "Guidelines for Soldering Surface Mount Components to PC Boards"
- RoHS Compliant
- Qualified to AEC Q101

Symbol



oolo Company

Packaging



JEDEC TO-252AA

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/

Reliability data can be found at: http://www.fairchildsemi.com/products/discrete/reliability/index.html.

All Fairchild semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

		UNITS
Drain to Source Voltage (Note 1) V _{DSS}	55	V
Drain to Gate Voltage (R _{GS} = 20kΩ) (Note 1) V _{DGR}	55	V
Gate to Source Voltage	±20	V
Drain Current		
Continuous (Figure 2)	20	A
Pulsed Drain Current	Figure 4	
Pulsed Avalanche Rating E _{AS}	Figures 6, 14, 15	
Power Dissipation P _D	93	W
Derate Above 25 ^o C	0.625	W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10sTL	300	°C
Package Body for 10s, See Techbrief 334	260	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST	CONDITIONS	MIN	ТҮР	MAX	UNITS
OFF STATE SPECIFICATIONS							
Drain to Source Breakdown Voltage	BV _{DSS}	$I_{D} = 250 \mu A, V_{GS} = 0V$ (Figure 11)		55	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 50V, V_{GS} =	0V	-	-	1	μA
		V_{DS} = 45V, V_{GS} =	0V, T _C = 150 ^o C	-	-	250	μA
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 20V$		-	-	±100	nA
ON STATE SPECIFICATIONS		<u> </u>					
Gate to Source Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 28$	50μA (Figure 10)	2	-	4	V
Drain to Source On Resistance	r _{DS(ON)}	I _D = 20A, V _{GS} = 10	V (Figure 9)	-	0.030	0.036	Ω
THERMAL SPECIFICATIONS							
Thermal Resistance Junction to Case	$R_{ extsf{ heta}JC}$	(Figure 3)		-	-	1.6	°C/W
Thermal Resistance Junction to Ambient	R _{θJA}	TO-251, TO-252		-	-	100	°C/W
SWITCHING SPECIFICATIONS ($V_{GS} = 10^{10}$	/)						
Turn-On Time	ton	$V_{DD} = 30V, I_D \cong 20A,$ $R_L = 1.5\Omega, V_{GS} = 10V,$ $R_{GS} = 25\Omega$		-	-	100	ns
Turn-On Delay Time	t _{d(ON)}			-	11	-	ns
Rise Time	tr			-	55	-	ns
Turn-Off Delay Time	td(OFF)			-	47	-	ns
Fall Time	t _f			-	66	-	ns
Turn-Off Time	tOFF			-	-	170	ns
GATE CHARGE SPECIFICATIONS							
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to 20V	$V_{DD} = 30V,$	-	36	44	nC
Gate Charge at 10V	Q _{g(10)}	$V_{GS} = 0V$ to 10V	l _D ≅ 20A, R _L = 1.5Ω	-	21	26	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V \text{ to } 2V$ $I_{g(REF)} = 1.0 \text{mA}$		-	1.3	1.6	nC
Gate to Source Gate Charge	Q _{gs}		(Figure 13)	-	3	-	nC
Reverse Transfer Capacitance	Q _{gd}			-	9	-	nC

Electrical Specifications $T_{C} = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
CAPACITANCE SPECIFICATIONS						
Input Capacitance	C _{ISS}	$V_{\text{DS}} = 25 \text{V}, V_{\text{GS}} = 0 \text{V},$	-	680	-	pF
Output Capacitance	C _{OSS}	f = 1MHz (Figure 12)	-	270	-	pF
Reverse Transfer Capacitance	C _{RSS}		-	60	-	pF

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 20A	-	-	1.25	V
Reverse Recovery Time	t _{rr}	I_{SD} = 20A, dI_{SD}/dt = 100A/µs	-	-	59	ns
Reverse Recovered Charge	Q _{RR}	$I_{SD} = 20A$, $dI_{SD}/dt = 100A/\mu s$	-	-	82	nC

Typical Performance Curves

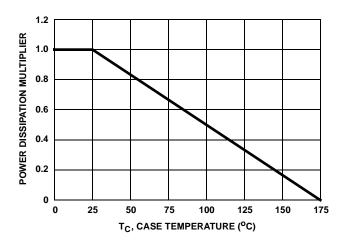


FIGURE 1. NORMALIZED POWER DISSIPATION vs CASE TEMPERATURE

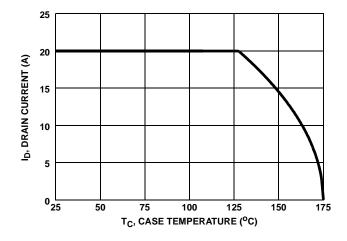


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs CASE TEMPERATURE

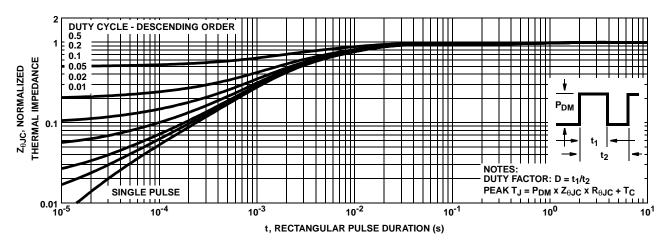
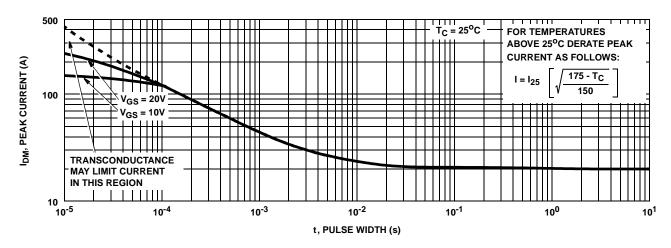


FIGURE 3. NORMALIZED MAXIMUM TRANSIENT THERMAL IMPEDANCE







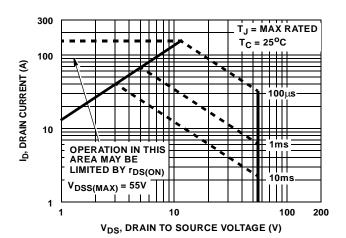


FIGURE 5. FORWARD BIAS SAFE OPERATING AREA

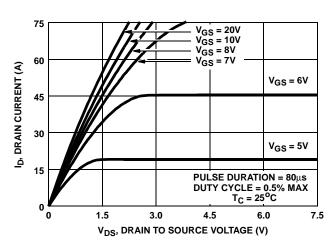
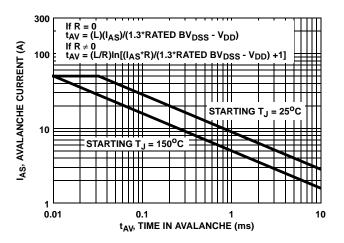
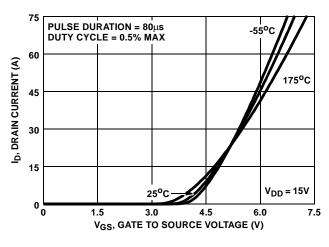


FIGURE 7. SATURATION CHARACTERISTICS

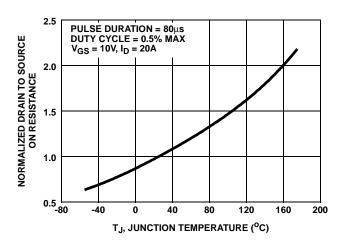


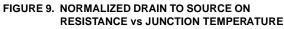
NOTE: Refer to Fairchild Application Notes AN9321 and AN9322. FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING CAPABILITY





Typical Performance Curves (Continued)





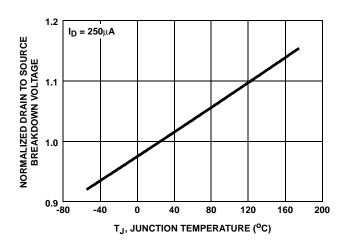


FIGURE 11. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE

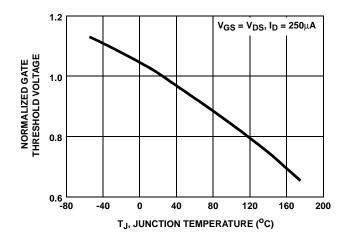
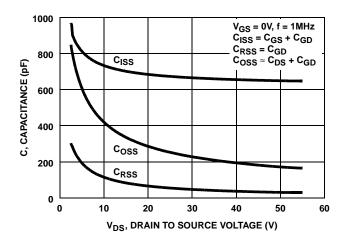
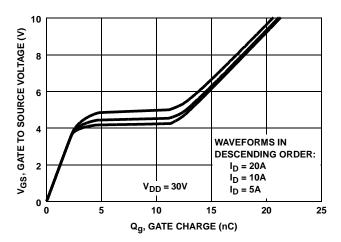
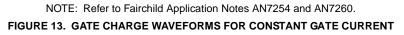


FIGURE 10. NORMALIZED GATE THRESHOLD VOLTAGE vs JUNCTION TEMPERATURE









Test Circuits and Waveforms

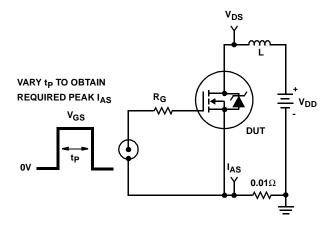


FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

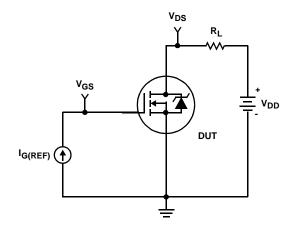


FIGURE 16. GATE CHARGE TEST CIRCUIT

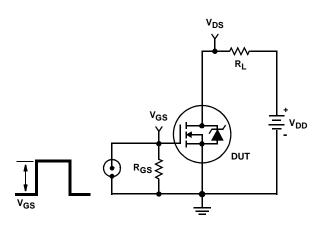


FIGURE 18. SWITCHING TIME TEST CIRCUIT

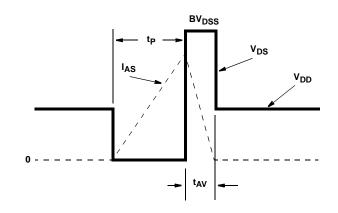


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS

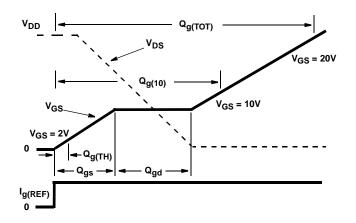


FIGURE 17. GATE CHARGE WAVEFORM

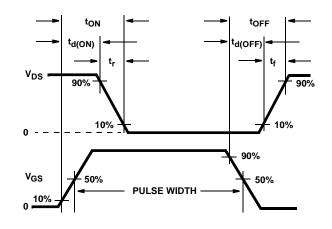


FIGURE 19. RESISTIVE SWITCHING WAVEFORMS

PSPICE Electrical Model

.SUBCKT HUFA75321D 2 1 3 ; rev 4/29/98

CA 12 8 9.96e-10 CB 15 14 9.83e-10 CIN 6 8 6.18e-10

DBODY 7 5 DBODYMOD DBREAK 5 11 DBREAKMOD DPLCAP 10 5 DPLCAPMOD

EBREAK 11 7 17 18 59.54 EDS 14 8 5 81 EGS 13 8 6 81 ESG 6 10 6 8 1 EVTHRES 6 21 19 8 1 EVTEMP 20 6 18 22 1

IT 8 17 1

LDRAIN 2 5 1e-9 LGATE 1 9 3.57e-9 LSOURCE 3 7 4.25e-9

MMED 16 6 8 8 MMEDMOD MSTRO 16 6 8 8 MSTROMOD MWEAK 16 21 8 8 MWEAKMOD

RBREAK 17 18 RBREAKMOD 1 RDRAIN 50 16 RDRAINMOD 5.50e-3 RGATE 9 20 2.25 RLDRAIN 2 5 10 RLGATE 1 9 35.7 RLSOURCE 3 7 42.5 RSLC1 5 51 RSLCMOD 1e-6 RSLC2 5 50 1e3 RSOURCE 8 7 RSOURCEMOD 16.30e-3 RVTHRES 22 8 RVTHRESMOD 1 RVTEMP 18 19 RVTEMPMOD 1

S1A 6 12 13 8 S1AMOD S1B 13 12 13 8 S1BMOD S2A 6 15 14 13 S2AMOD S2B 13 15 14 13 S2BMOD

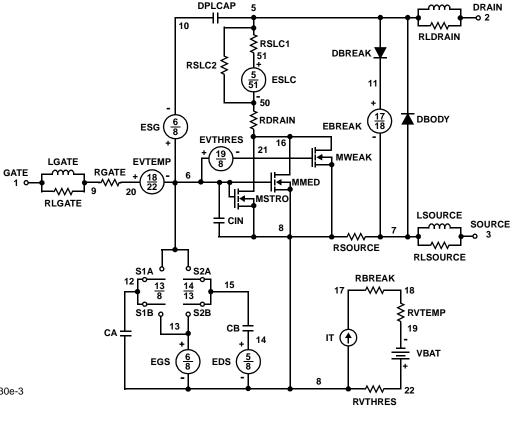
VBAT 22 19 DC 1

ESLC 51 50 VALUE={(V(5,51)/ABS(V(5,51)))*(PWR(V(5,51)/(1e-6*101),2.5))}

.MODEL DBODYMOD D (IS = 7.47e-13 RS = 6.45e-3 TRS1 = 2.01e-3 TRS2 = 1.21e-6 CJO = 1.02e-9 TT = 3.21e-8 M = 0.50) .MODEL DBREAKMOD D (RS = 2.01e- 1TRS1 = 3.62e- 3TRS2 = 6.01e-7) .MODEL DPLCAPMOD D (CJO = 9.0e-1 0IS = 1e-3 0N = 10 M = 0.85) .MODEL MMEDMOD NMOS (VTO = 3.25 KP = 1.75 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u RG = 2.25) .MODEL MSTROMOD NMOS (VTO = 3.65 KP = 32.00 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u) MODEL MWEAKMOD NMOS (VTO = 2.91 KP = 0.07 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u RG = 22.5 RS = 0.1) .MODEL RBREAKMOD RES (TC1 = 1.05e- 3TC2 = 1.21e-7) MODEL RDRAINMOD RES (TC1 = 2.40e-2 TC2 = 1.02e-6) .MODEL RSLCMOD RES (TC1 = 2.07e-4 TC2 = 4.67e-5) .MODEL RSOURCEMOD RES (TC1 = 0 TC2 =0) MODEL RVTHRESMOD RES (TC = -3.01e-3 TC2 = -8.85e-6) .MODEL RVTEMPMOD RES (TC1 = -1.96e- 3TC2 = 1.39e-6) .MODEL S1AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -7.85 VOFF= -4.85) .MODEL S1BMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -4.85 VOFF= -7.85) .MODEL S2AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = 0.00 VOFF= 3.00) .MODEL S2AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = 3.00 VOFF= 0.00)

.ENDS

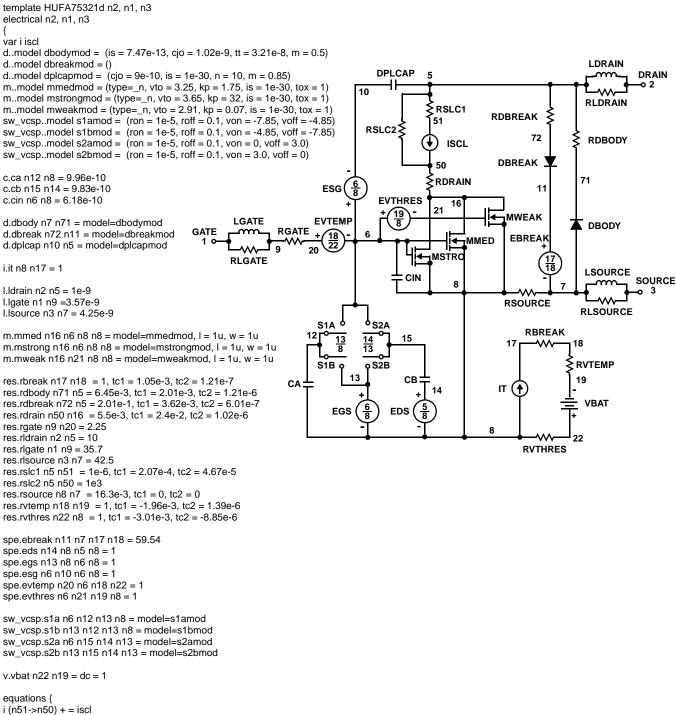
NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.



LDRAIN

SABER Electrical Model

REV April 1998



 $\sum_{n=1}^{n} \sum_{n=1}^{n} \sum_{$

SPICE Thermal Model

REV 24 February 1999

HUFA75321D

CTHERM1 th 6 2.7e-3 CTHERM2 6 5 3.7e-3 CTHERM3 5 4 1.2e-2 CTHERM4 4 3 3.8e-3 CTHERM5 3 2 1.4e-2 CTHERM6 2 tl 10.55

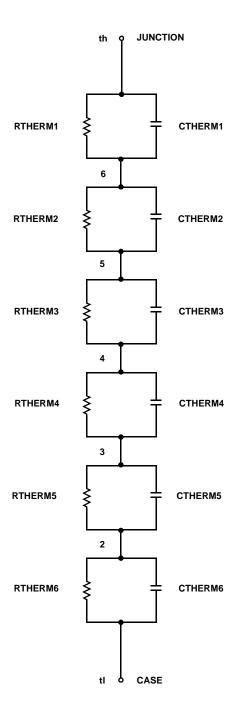
RTHERM1 th 6 1.10e-2 RTHERM2 6 5 2.72e-2 RTHERM3 5 4 7.67e-2 RTHERM4 4 3 4.30e-1 RTHERM5 3 2 6.49e-1 RTHERM6 2 tl 8.61e-2

SABER Thermal Model

SABER thermal model HUFA75321D

template thermal_model th tl thermal_c th, tl { ctherm.ctherm1 th 6 = 2.7e-3 ctherm.ctherm2 6 5 = 3.7e-3 ctherm.ctherm3 5 4 = 1.2e-2 ctherm.ctherm4 4 3 = 3.8-3 ctherm.ctherm5 3 2 = 1.4e-2 ctherm.ctherm6 2 tl = 10.55

rtherm.rtherm1 th 6 = 1.10e-3rtherm.rtherm2 6 5 = 2.72e-2rtherm.rtherm3 5 4 = 7.67e-2rtherm.rtherm4 4 3 = 4.30e-1rtherm.rtherm5 3 2 = 6.49e-1rtherm.rtherm6 2 tl = 8.61e-2





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